

DC-TO-DC CONVERTER CONTROL CIRCUITS

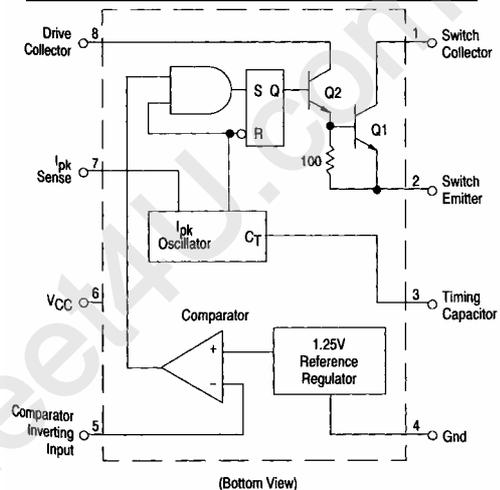
IL34063A

The IL34063A is a monolithic control circuit containing the primary functions required for DC-to-DC converters. These devices consist of an internal temperature compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This series was specifically designed to be incorporated in Step-Down and Step-Up and Voltage-Inverting applications with a minimum number of external components.

FEATURES

- Operation from 3.0 V to 40 V Input
- Low Standby Current
- Current Limiting
- Output Switch Current to 1.5 A
- Output Voltage Adjustable
- Frequency Operation to 100 kHz
- Precision 2% Reference

FUNCTIONAL BLOCK DIAGRAM

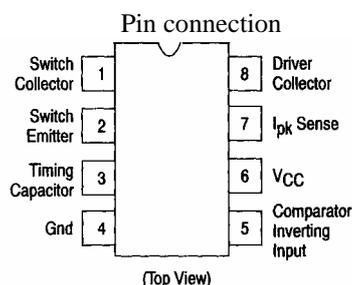


MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	40	Vdc
Comparator Input Voltage Range	V _{IR}	-0.3 to +40	Vdc
Switch Collector Voltage	V _{C(switch)}	40	Vdc
Switch Emitter Voltage (V _{pin 1} = 40 V)	V _{E(switch)}	40	Vdc
Switch Collector to Emitter Voltage	V _{CE(switch)}	40	Vdc
Driver Collector Voltage	I _{C(driver)}	40	Vdc
Driver Collector Current (Note 1)	I _{C(driver)}	100	mA
Switch Current	I _{SW}	1.5	A
Power Dissipation and Thermal Characteristics			
Ceramic Package, U Suffix T _A = +25°C	P _D	1.25	W
Thermal Resistance	R _{θJA}	100	°C/W
Plastic Package, P Suffix T _A = +25°C	P _D	1.25	W
Thermal Resistance	R _{θJA}	100	°C/W
SOIC Package, D Suffix T _A = +25°C	P _D	625	mW
Thermal Resistance	R _{θJA}	160	°C/W
Operating Junction Temperature	T _J	+150	°C
Operating Ambient Temperature Range	T _A	-40 to +85	°C
Storage Temperature Range	T _{stg}	-65to+150	°C

ORDERING INFORMATION

Device	Temperature Range	Package
34063AD	-40° to +85°C	SO-8
34063AN		Plastic DIP



ELECTRICAL CHARACTERISTICS

(V_{CC} = 5.0 V, T_A = -40 to +85°C unless otherwise specified.)

Characteristics	Symbol	Min	Typ	Max	Unit
OSCILLATOR					
Frequency (V _{Pin5} = 0 V, C _T = 1.0 nF, T _A = 25°C)	fosc	24	33	42	kHz
Charge Current (V _{CC} = 5.0 V to 40 V, T _A = 25°C)	I _{chg}	24	33	42	μA
Discharge Current (V _{CC} = 5.0 V to 40 V, T _A = 25°C)	I _{dischg}	140	200	260	μA
Discharge to Charge Current Ratio (Pin7 to V _{CC} , T _A = 25°C)	I _{dischg} /I _{chg}	5.2	6.2	7.5	—
Current Limit Sense Voltage (I _{chg} = I _{dischg} , T _A = 25°C)	V _{lpk(sense)}	250	300	350	mV
OUTPUT SWITCH (Note 3)					
Saturation Voltage, Darlington Connection (I _{SW} = 1.0 A, Pins 1, 8 connected)	V _{CE(sat)}	—	1.0	1.3	V
Saturation Voltage (I _{SW} = 1.0 A, R _{Pin8} = 82 Ω to V _{CC} . Forced β = 20)	V _{CE(sat)}	—	0.45	0.7	V
DC Current Gain (I _{SW} = 1.0 A, V _{CE} = 5.0 V, T _A = 25°C)	h _{FE}	50	120	—	—
Collector Off-State Current (V _{CE} = 40V)	I _{C(off)}	—	0.01	100	μA
COMPARATOR					
Threshold Voltage (T _A = 25°C) (T _A = T _{LOW} to T _{HIGH})	V _{th}	1.225 1.21	1.25 —	1.275 1.29	V
Threshold Voltage (T_A = 25°C) **	V_{th}	1.2375	1.25	1.2625	V
Threshold Voltage Line Regulation (V _{CC} = 3.0 V to 40 V)	Reg _{line}	—	1.4	5.0	mV
Input Bias Current (V _{in} = 0V)	I _{IB}	—	-40	-400	nA
TOTAL DEVICE					
Supply Current (V _{CC} = 5.0 V to 40 V, C _T = 1.0 nF, V _{pin7} = V _{CC} . V _{Pin5} > V _{th} , Pin 2 = Gnd, Remaining pins open)	I _{CC}	—	2.5	4.0	mA

NOTES:

- Maximum package power dissipation limits must be observed.
- Low duty cycle pulse techniques are used during test to maintain Junction temperature as close to ambient temperature as possible
- If the output switch is driven into hard saturation (non Darlington configuration) at low switch currents (< 300 mA) and high driver currents (>30 mA), it may take up to 2.0 μs to come out of saturation This condition will shorten the off' time at frequencies > 30 kHz, and is magnified at high temperatures This condition does not occur with a Darlington configuration, since the output switch cannot saturate If a non Darlington configuration is used, the following output drive condition is recommended
Forced β of output switch = I_C, output/(I_C, driver -7.0 mA*) > 10

*The 100 Ω. resistor in the emitter of the driver device requires about 7.0 mA before the output switch conducts

**Possible version for shipment

ELECTRICAL CHARACTERISTICS

(V_{CC} = 3.3 V, T_A = -40 to +85°C unless otherwise specified.)

Characteristics	Symbol	Min	Typ	Max	Unit
OSCILLATOR					
Frequency (V _{Pin5} = 0 V, C _T = 1.0 nF, T _A = 25°C)	fosc	24	33	42	kHz
Charge Current (V _{CC} = 5.0 V to 40 V, T _A = 25°C)	I _{chg}	24	33	42	μA
Discharge Current (V _{CC} = 5.0 V to 40 V, T _A = 25°C)	I _{dischg}	140	200	260	μA
Discharge to Charge Current Ratio (Pin7 to V _{CC} , T _A = 25°C)	I _{dischg} /I _{chg}	5.2	6.2	7.5	—
Current Limit Sense Voltage (I _{chg} = I _{dischg} , T _A = 25°C)	V _{lpk(sense)}	250	300	350	mV
OUTPUT SWITCH (Note 3)					
Saturation Voltage, Darlington Connection (I _{SW} = 1.0 A, Pins 1, 8 connected)	V _{CE(sat)}	—	1.0	1.3	V
Saturation Voltage (I _{SW} = 1.0 A, R _{Pin8} = 82 Ω to V _{CC} . Forced β = 20)	V _{CE(sat)}	—	0.45	0.7	V
DC Current Gain (I _{SW} = 1.0 A, V _{CE} = 5.0 V, T _A = 25°C)	h _{FE}	50	120	—	—
Collector Off-State Current (V _{CE} = 40V)	I _{C(off)}	—	0.01	100	μA
COMPARATOR					
Threshold Voltage (T _A = 25°C) (T _A = T _{LOW} to T _{HIGH})	V _{th}	1.225 1.21	1.25 —	1.275 1.29	V
Threshold Voltage (T_A = 25°C) **	V_{th}	1.2375	1.25	1.2625	V
Threshold Voltage Line Regulation (V _{CC} = 3.0 V to 40 V)	Reg _{line}	—	1.4	5.0	mV
Input Bias Current (V _{in} = 0V)	I _{IB}	—	-40	-400	nA
TOTAL DEVICE					
Supply Current (V _{CC} = 5.0 V to 40 V, C _T = 1.0 nF, V _{Pin7} = V _{CC} . V _{Pin5} > V _{th} , Pin 2 = Gnd, Remaining pins open)	I _{CC}	—	2.5	4.0	mA

NOTES:

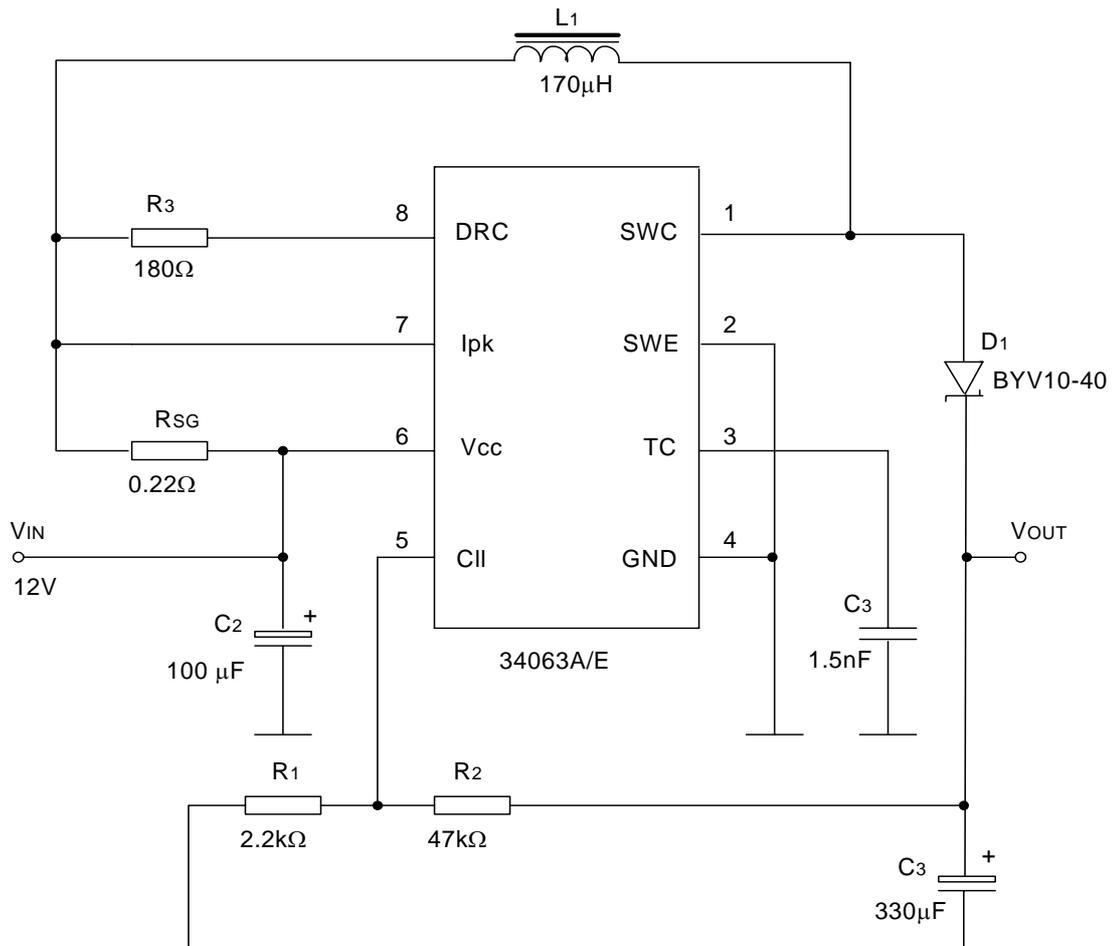
- Maximum package power dissipation limits must be observed.
- Low duty cycle pulse techniques are used during test to maintain Junction temperature as close to ambient temperature as possible
- If the output switch is driven into hard saturation (non Darlington configuration) at low switch currents (< 300 mA) and high driver currents (>30 mA), it may take up to 2.0 μs to come out of saturation This condition will shorten the off time at frequencies > 30 kHz, and is magnified at high temperatures This condition does not occur with a Darlington configuration, since the output switch cannot saturate If a non Darlington configuration is used, the following output drive condition is recommended
Forced β of output switch = I_C, output/(I_C, driver -7.0 mA*) > 10

*The 100 Ω resistor in the emitter of the driver device requires about 7.0 mA before the output switch conducts

**Possible version for shipment

TYPICAL APPLICATION CIRCUIT

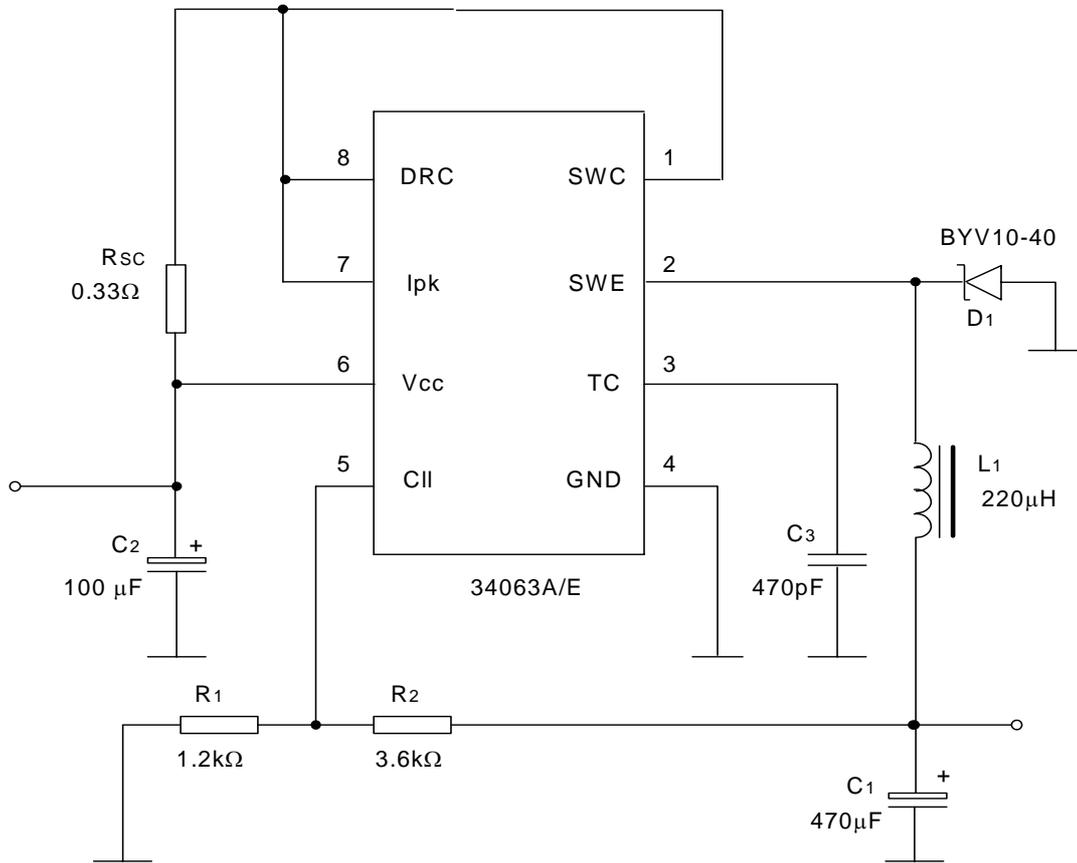
Step-Up Converter



Test Condition ($V_{OUT} = 28\text{ V}$)

Test	Conditions	Value (Typ)	Unit
Line Regulation	$V_{IN} = 8\text{ to }16\text{ V}, I_O = 175\text{ mA}$	30	mV
Load Regulation	$V_{IN} = 12\text{ V}, I_O = 75\text{ to }175\text{ mA}$	10	mV
Output Ripple	$V_{IN} = 12\text{ V}, I_O = 175\text{ mA}$	300	mV
Efficiency	$V_{IN} = 12\text{ V}, I_O = 175\text{ mA}$	89	%

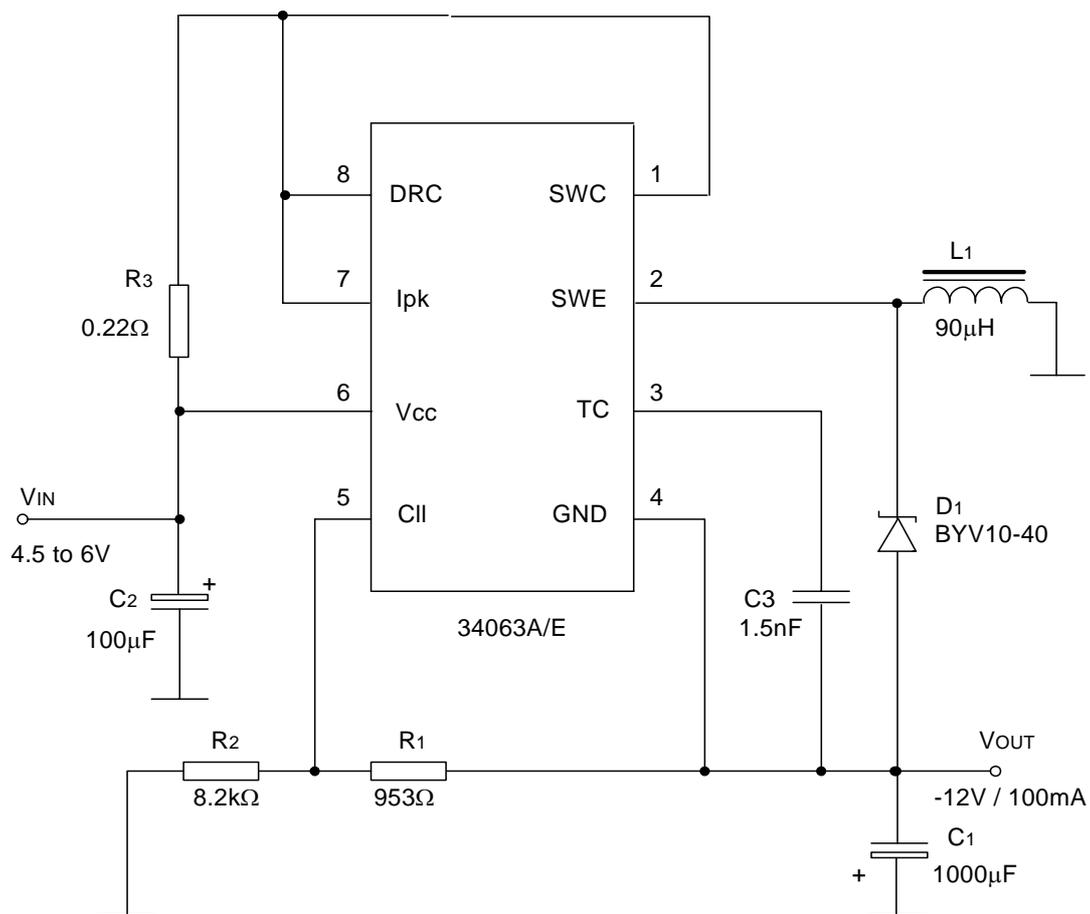
Step-Down Converter



Test Condition ($V_{OUT} = 5\text{ V}$)

Test	Conditions	Value (Typ)	Unit
Line Regulation	$V_{IN} = 15\text{ to }25\text{ V}$, $I_O = 500\text{ mA}$	5	mV
Load Regulation	$V_{IN} = 25\text{ V}$, $I_O = 50\text{ to }500\text{ mA}$	30	mV
Output Ripple	$V_{IN} = 25\text{ V}$, $I_O = 500\text{ mA}$	100	mV
Efficiency	$V_{IN} = 25\text{ V}$, $I_O = 500\text{ mA}$	80	%
ISC	$V_{IN} = 25\text{ V}$, $R_{LOAD} = 0.1\ \Omega$	1.2	A

Voltage Inverting Converter



Test Condition ($V_{OUT} = -12\text{ V}$)

Test	Conditions	Value (Typ)	Unit
Line Regulation	$V_{IN} = 4.5\text{ to }6\text{ V}, I_O = 100\text{ mA}$	15	mV
Load Regulation	$V_{IN} = 5\text{ V}, I_O = 10\text{ to }100\text{ mA}$	20	mV
Output Ripple	$V_{IN} = 5\text{ V}, I_O = 100\text{ mA}$	230	mV
Efficiency	$V_{IN} = 5\text{ V}, I_O = 100\text{ mA}$	58	%
ISC	$V_{IN} = 5\text{ V}, R_{LOAD} = 0.1\ \Omega$	0.9	A

Calculation

Parameter	Step-Up (Discontinuous mode)	Step-Down (Continuous mode)	Voltage Inverting (Discontinuous mode)
t_{on}/t_{off}	$\frac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\frac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\frac{ V_{out} + V_F}{V_{in} - V_{sat}}$
$(t_{on} + t_{off})_{max}$	$\frac{1}{f_{min}}$	$\frac{1}{f_{min}}$	$\frac{1}{f_{min}}$
C_T	$4.5 \times 10^{-5} t_{on}$	$4.5 \times 10^{-5} t_{on}$	$4.5 \times 10^{-5} t_{on}$
$I_{PK(switch)}$	$2I_{out(max)}[(t_{on}/t_{off})+1]$	$2I_{out(max)}$	$2I_{out(max)}[(t_{on}/t_{off})+1]$
R_{SC}	$0.3/I_{PK(switch)}$	$0.3/I_{PK(switch)}$	$0.3/I_{PK(switch)}$
C_O	$\equiv \frac{I_{out} t_{on}}{V_{ripple(p-p)}}$	$\frac{I_{PK(switch)} (t_{on} + t_{off})}{8V_{ripple(p-p)}}$	$\equiv \frac{I_{out} t_{on}}{V_{ripple(p-p)}}$
$L(min)$	$\frac{V_{in(min)} - V_{sat}}{I_{PK(switch)}} t_{on(max)}$	$\frac{V_{in(min)} - V_{sat} - V_{out}}{I_{PK(switch)}} t_{on(max)}$	$\frac{V_{in(min)} - V_{sat}}{I_{PK(switch)}} t_{on(max)}$

NOTES:

V_{sat} = Saturation voltage of the output switch

V_F = Forward voltage drop of the output rectifier

THE FOLLOWING POWER SUPPLY CHARACTERISTICS MUST BE CHOSEN:

V_{in} = Nominal input voltage

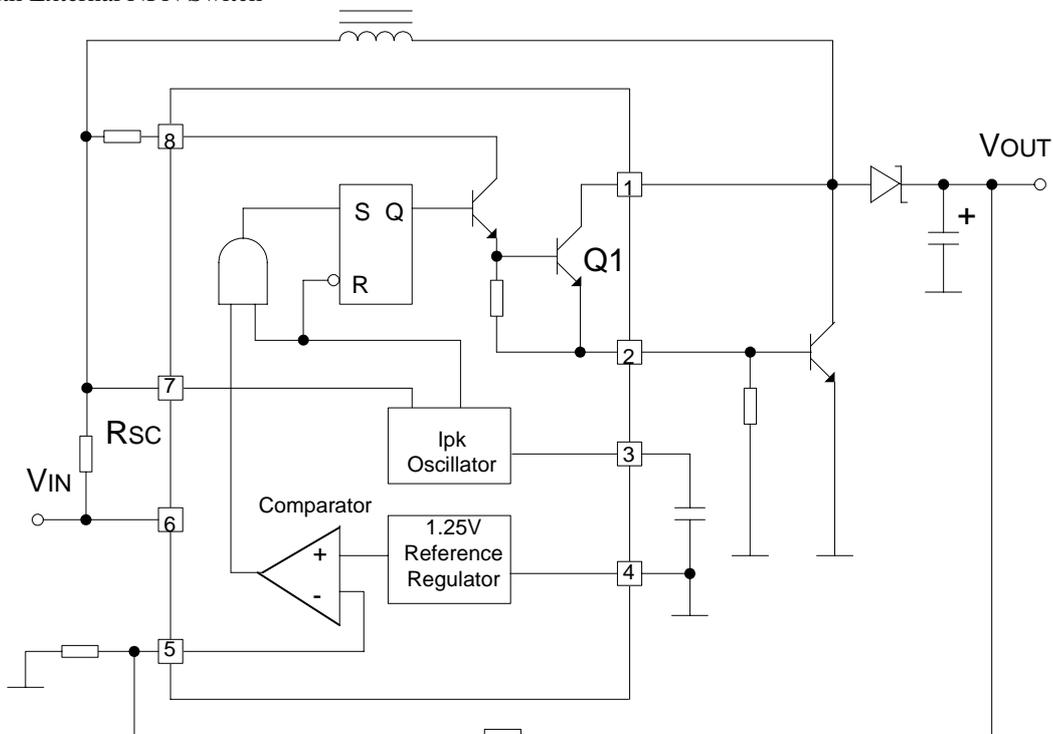
V_{out} = Desired output voltage, $|V_{out}| = 1.25(1+R_2/R_1)$

I_{out} = Desired output current

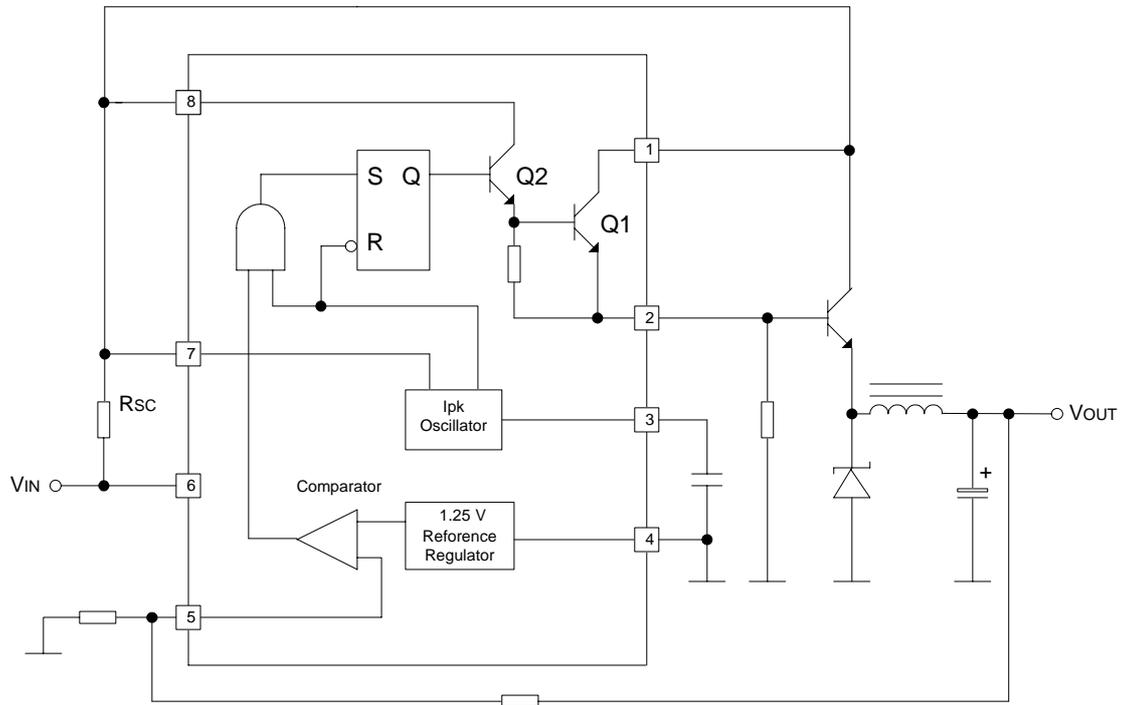
f_{min} = Minimum desired output switching frequency at the selected values of V_{in} and I_o

V_{ripple} = Desired peak to peak output ripple voltage. In practice, the calculated capacitor value will and to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.

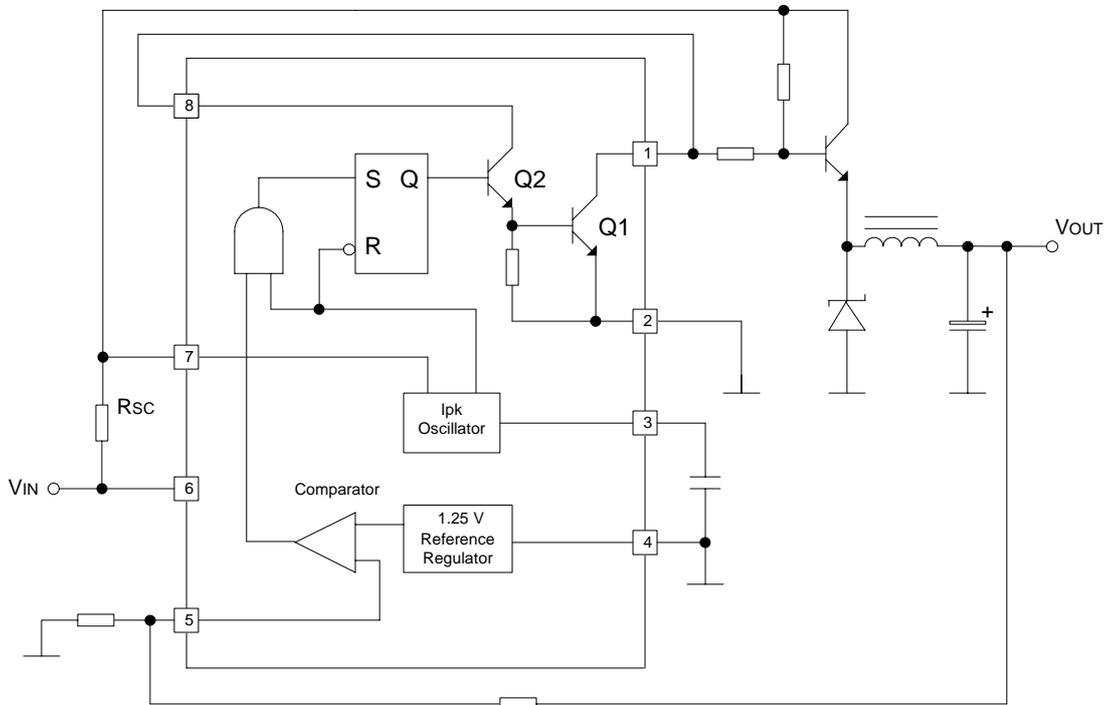
Step-up With External NPN Switch



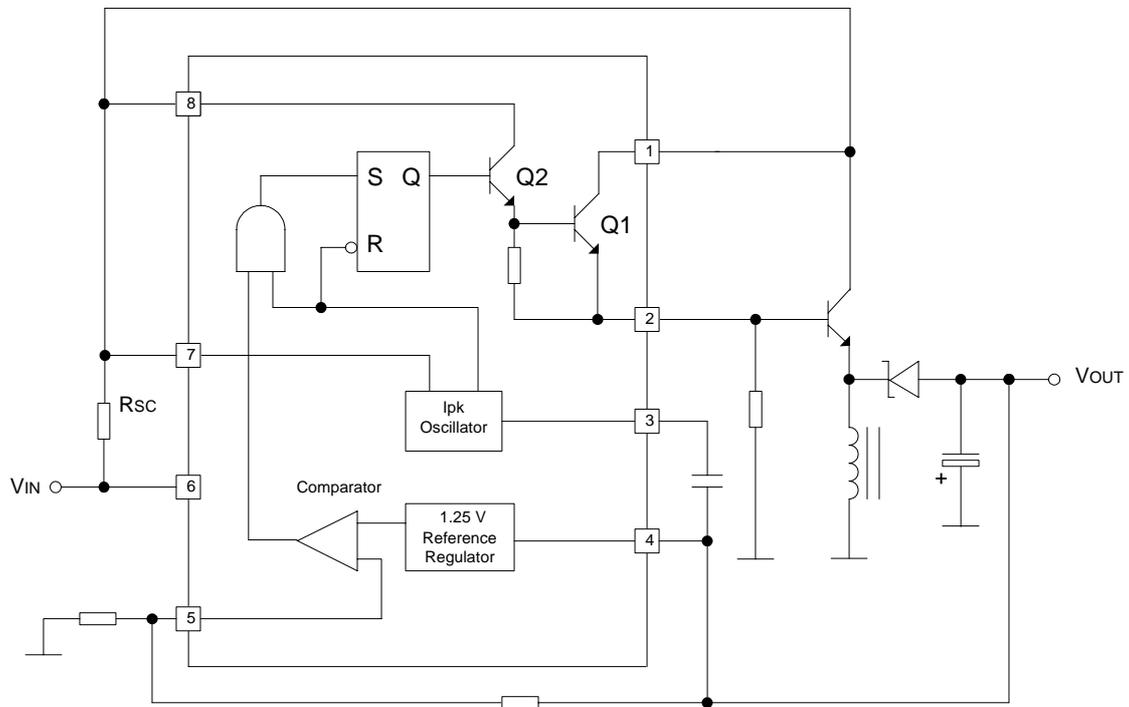
Step-down With External NPN Switch



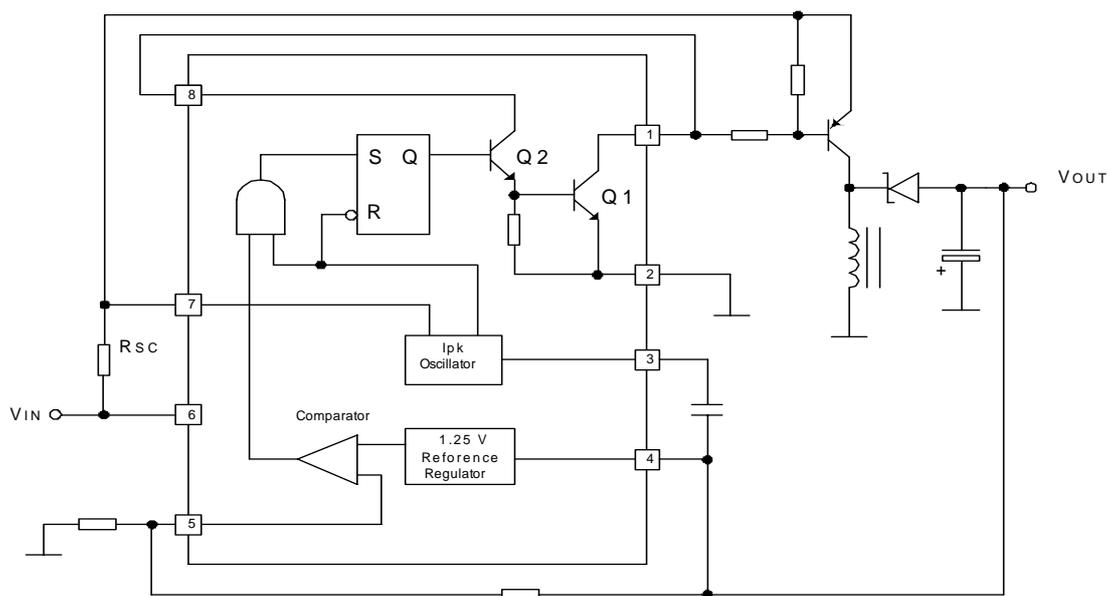
Step-down With External PNP Switch



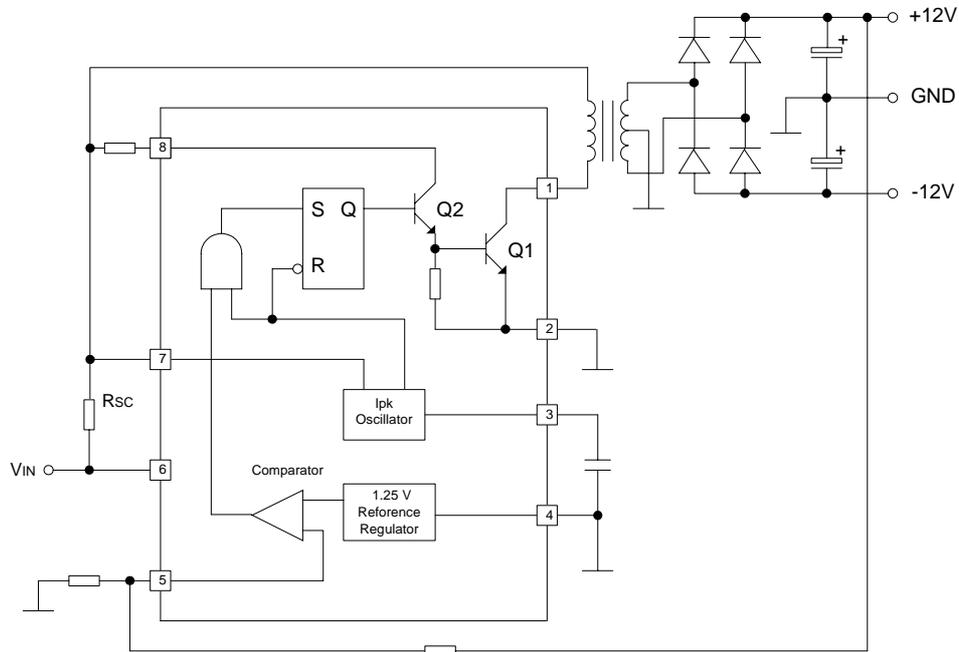
Voltage Inverting With External NPN Switch



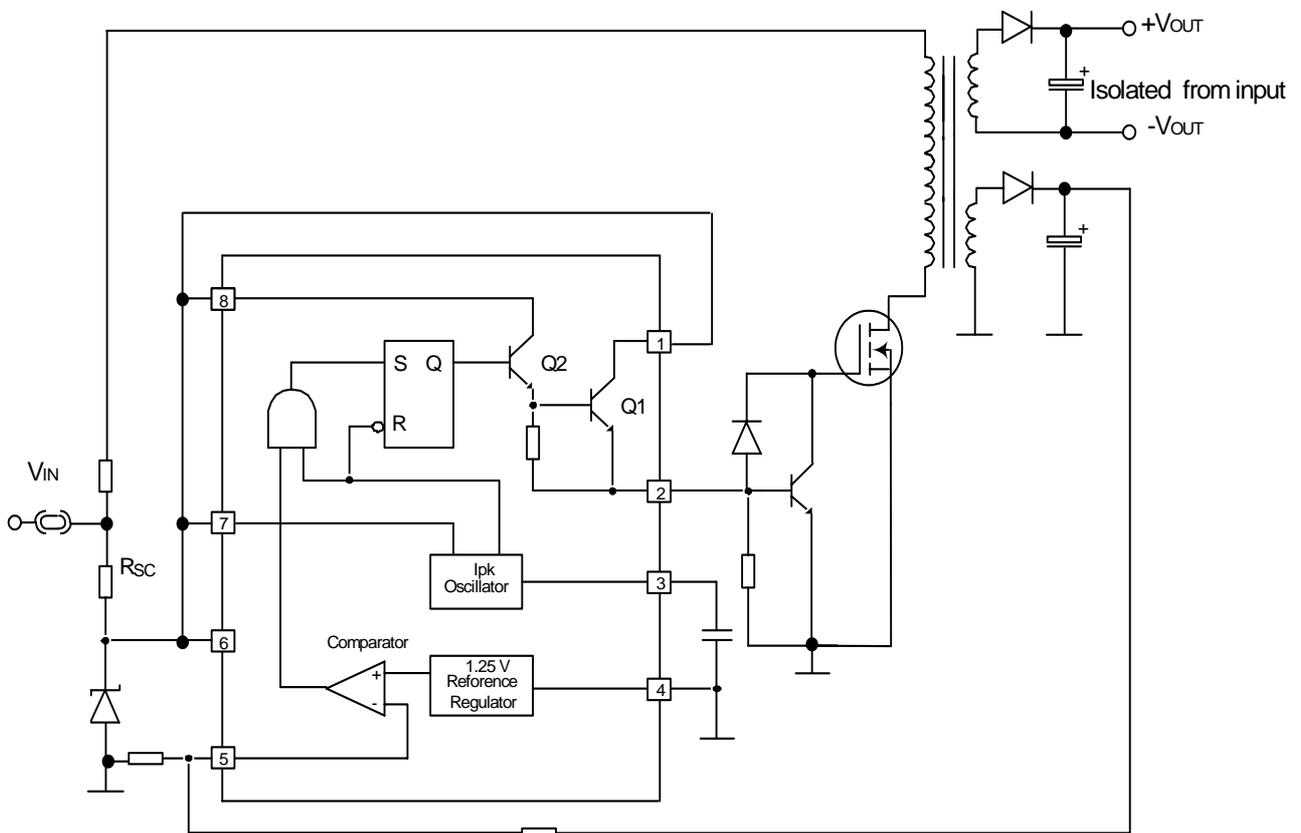
Voltage Inverting With External PNP Saturated Switch



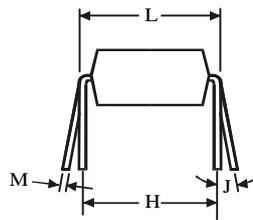
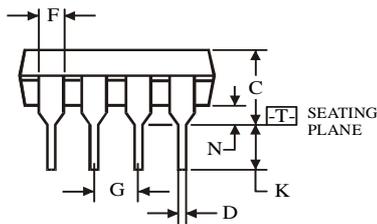
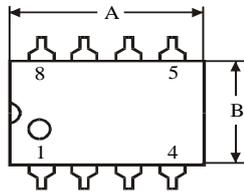
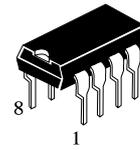
Dual Output Voltage



Higher Output Power, Higher Input Voltage



**N SUFFIX PLASTIC DIP
(MS - 001BA)**



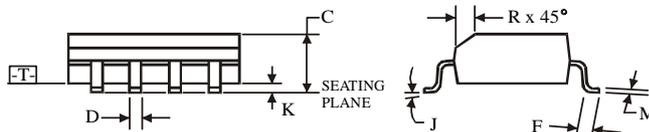
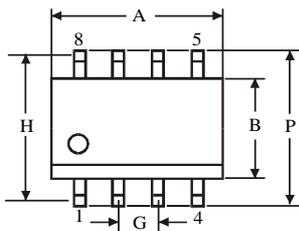
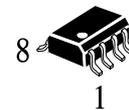
$\oplus 0.25 (0.010) \text{ (M) T}$

Symbol	Dimension, mm	
	MIN	MAX
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

NOTES:

- Dimensions "A", "B" do not include mold flash or protrusions.
Maximum mold flash or protrusions 0.25 mm (0.010) per side.

**D SUFFIX SOIC
(MS - 012AA)**



$\oplus 0.25 (0.010) \text{ (M) T C (M)}$

Symbol	Dimension, mm	
	MIN	MAX
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

NOTES:

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side
for A; for B - 0.25 mm (0.010) per side.